

October 1987 Revised January 1999

# CD4049UBC • CD4050BC Hex Inverting Buffer • Hex Non-Inverting Buffer

#### **General Description**

The CD4049UBC and CD4050BC hex buffers are monolithic complementary MOS (CMOS) integrated circuits constructed with N- and P-channel enhancement mode transistors. These devices feature logic level conversion using only one supply voltage (V $_{\rm DD}$ ). The input signal high level (V $_{\rm IH}$ ) can exceed the V $_{\rm DD}$  supply voltage when these devices are used for logic level conversions. These devices are intended for use as hex buffers, CMOS to DTL/TTL converters, or as CMOS current drivers, and at V $_{\rm DD}=5.0$ V, they can drive directly two DTL/TTL loads over the full operating temperature range.

#### **Features**

- Wide supply voltage range: 3.0V to 15V
- Direct drive to 2 TTL loads at 5.0V over full temperature range
- High source and sink current capability
- $\blacksquare$  Special input protection permits input voltages greater than  $V_{DD}$

#### **Applications**

- · CMOS hex inverter/buffer
- · CMOS to DTL/TTL hex converter
- · CMOS current "sink" or "source" driver
- · CMOS HIGH-to-LOW logic level converter

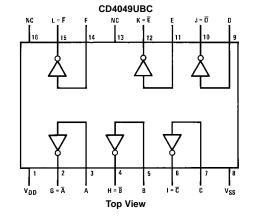
### **Ordering Code:**

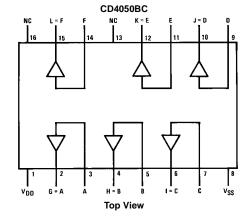
Order Number	Package Number	Package Description
CD4049UBCM	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
CD4049UBCN	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
CD4050BCM	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
CD4050BCN	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

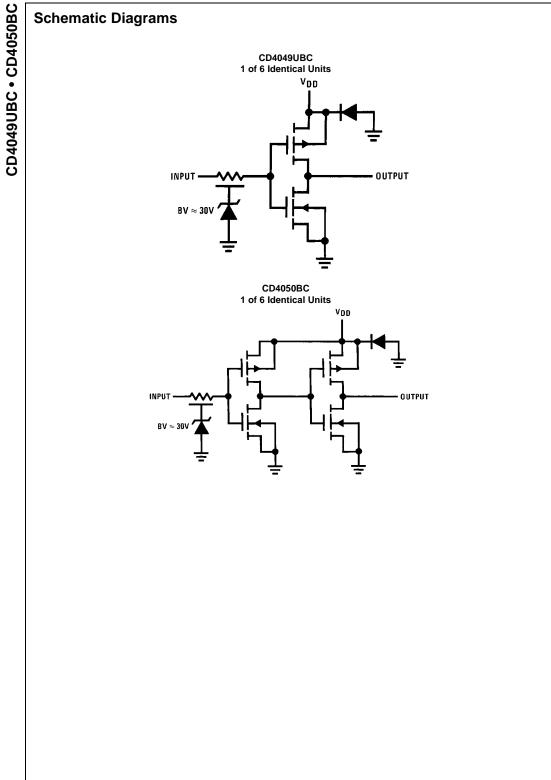
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

### **Connection Diagrams**

#### Pin Assignments for DIP







## **Absolute Maximum Ratings**(Note 1)

(Note 2)

Supply Voltage (V<sub>DD</sub>) -0.5V to +18V Input Voltage (V<sub>IN</sub>) -0.5V to +18V Voltage at Any Output Pin (V<sub>OUT</sub>) -0.5V to  $V_{DD} + 0.5V$ 

Storage Temperature Range (T<sub>S</sub>)  $-65^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ 

Power Dissipation (P<sub>D</sub>)

Dual-In-Line 700 mW Small Outline 500 mW

Lead Temperature (T<sub>L</sub>)

(Soldering, 10 seconds) 260°C

### **Recommended Operating** Conditions (Note 2)

Supply Voltage (V<sub>DD</sub>) 3V to 15V 0V to 15V Input Voltage (V<sub>IN</sub>) Voltage at Any Output Pin  $(V_{OUT})$ 0 to V<sub>DD</sub>

Operating Temperature Range (T<sub>A</sub>)

CD4049UBC, CD4050BC -40°C to +85°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides

conditions for actual device operation.

Note 2: V<sub>SS</sub> = 0V unless otherwise specified.

#### **DC Electrical Characteristics** (Note 3)

Symbol	Parameter	Conditions	-40	-40°C		+25°C		+85°C		Units
		Conditions	Min	Max	Min	Тур	Max	Min	Max	Units
I <sub>DD</sub>	Quiescent Device Current	$V_{DD} = 5V$		4		0.03	4.0		30	μΑ
		$V_{DD} = 10V$		8		0.05	8.0		60	μΑ
		$V_{DD} = 15V$		16		0.07	16.0		120	μΑ
V <sub>OL</sub>	LOW Level Output Voltage	$V_{IH} = V_{DD}, V_{IL} = 0V,$								
		$ I_O  < 1 \mu A$								
		$V_{DD} = 5V$		0.05		0	0.05		0.05	V
		$V_{DD} = 10V$		0.05		0	0.05		0.05	V
		$V_{DD} = 15V$		0.05		0	0.05		0.05	V
V <sub>OH</sub>	HIGH Level Output Voltage	$V_{IH} = V_{DD}, V_{IL} = 0V,$								
		$ I_O  < 1 \mu A$								
		$V_{DD} = 5V$	4.95		4.95	5		4.95		V
		$V_{DD} = 10V$	9.95		9.95	10		9.95		V
		$V_{DD} = 15V$	14.95		14.95	15		14.95	Max 30 60 120  0.05 0.05 0.05  1.5 3.0 4.0  1.0 2.0 3.0	V
V <sub>IL</sub>	LOW Level Input Voltage	$ I_O  < 1 \mu A$								
	(CD4050BC Only)	$V_{DD} = 5V, V_{O} = 0.5V$		1.5		2.25	1.5		1.5	V
		$V_{DD} = 10V, V_{O} = 1V$		3.0		4.5	3.0		3.0	V
		$V_{DD} = 15V, V_{O} = 1.5V$		4.0		6.75	4.0		4.0	V
V <sub>IL</sub>	LOW Level Input Voltage	I <sub>O</sub>   < 1 μA								
	(CD4049UBC Only)	$V_{DD} = 5V, V_{O} = 4.5V$		1.0		1.5	1.0		1.0	V
		$V_{DD} = 10V, V_{O} = 9V$		2.0		2.5	2.0		2.0	V
		$V_{DD} = 15V, V_{O} = 13.5V$		3.0		3.5	3.0		Max 30 60 120 0.05 0.05 0.05 1.5 3.0 4.0 1.0 2.0 3.0	V
V <sub>IH</sub>	HIGH Level Input Voltage	I <sub>O</sub>   < 1 μA								
	(CD4050BC Only)	$V_{DD} = 5V, V_{O} = 4.5V$	3.5		3.5	2.75		3.5		V
		$V_{DD} = 10V, V_{O} = 9V$	7.0		7.0	5.5		7.0		V
		$V_{DD} = 15V, V_{O} = 13.5V$	11.0		11.0	8.25		11.0		V
V <sub>IH</sub>	HIGH Level Input Voltage	I <sub>O</sub>   < 1 μA								
	(CD4049UBC Only)	$V_{DD} = 5V, V_{O} = 0.5V$	4.0		4.0	3.5		4.0		V
		$V_{DD} = 10V, V_{O} = 1V$	8.0		8.0	7.5		8.0		V
		$V_{DD} = 15V, V_{O} = 1.5V$	12.0		12.0	11.5		12.0	30 60 120 0.05 0.05 0.05 1.5 3.0 4.0 2.0 3.0	V
l <sub>OL</sub>	LOW Level Output Current	$V_{IH} = V_{DD}, V_{IL} = 0V$								
	(Note 4)	$V_{DD} = 5V, V_{O} = 0.4V$	4.6		4.0	5		3.2		mA
		$V_{DD} = 10V, V_{O} = 0.5V$	9.8		8.5	12		6.8		mA
		$V_{DD} = 15V, V_{O} = 1.5V$	29		25	40		20		mA
ОН	HIGH Level Output Current	$V_{IH} = V_{DD}, V_{IL} = 0V$								
	(Note 4)	$V_{DD} = 5V, V_{O} = 4.6V$	-1.0		-0.9	-1.6		-0.72		mA
		$V_{DD} = 10V, V_{O} = 9.5V$	-2.1		-1.9	-3.6		-1.5		mA
		$V_{DD} = 15V, V_{O} = 13.5V$	-7.1		-6.2	-12		-5	0.05 0.05 0.05 1.5 3.0 4.0 1.0 2.0 3.0	mA
I <sub>IN</sub>	Input Current	V <sub>DD</sub> = 15V, V <sub>IN</sub> = 0V	-0.3		-0.3	-10 <sup>-5</sup>			-1.0	μΑ
I <sub>IN</sub>		V <sub>DD</sub> = 15V, V <sub>IN</sub> = 15V	0.3		0.3	10 <sup>-5</sup>			1.0	μΑ

### DC Electrical Characteristics (Continued)

Note 4: These are peak output current capabilities. Continuous output current is rated at 12 mA maximum. The output current should not be allowed to exceed this value for extended periods of time. I<sub>OL</sub> and I<sub>OH</sub> are tested one output at a time.

#### **AC Electrical Characteristics** (Note 5)

 $T_A = 25$ °C,  $C_L = 50$  pF,  $R_L = 200$ k,  $t_r = t_f = 20$  ns, unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Units
t <sub>PHL</sub>	Propagation Delay Time	$V_{DD} = 5V$		30	65	ns
	HIGH-to-LOW Level	V <sub>DD</sub> = 10V		20	40	ns
		$V_{DD} = 15V$		15	30	ns
t <sub>PLH</sub>	Propagation Delay Time	$V_{DD} = 5V$		45	85	ns
	LOW-to-HIGH Level	$V_{DD} = 10V$		25	45	ns
		$V_{DD} = 15V$		20	35	ns
t <sub>THL</sub>	Transition Time	$V_{DD} = 5V$		30	60	ns
	HIGH-to-LOW Level	$V_{DD} = 10V$		20	40	ns
		$V_{DD} = 15V$		15	30	ns
t <sub>TLH</sub>	Transition Time	$V_{DD} = 5V$		60	120	ns
	LOW-to-HIGH Level	$V_{DD} = 10V$		30	55	ns
		$V_{DD} = 15V$		25	45	ns
C <sub>IN</sub>	Input Capacitance	Any Input		15	22.5	pF

Note 5: AC Parameters are guaranteed by DC correlated testing.

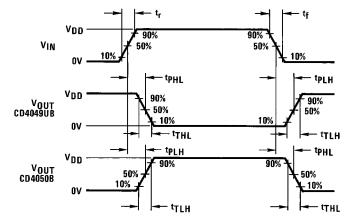
#### AC Electrical Characteristics (Note 6)

CD4050BC  $T_A=25^{\circ}C,\ C_L=50\ pF,\ R_L=200k,\ t_f=t_f=20\ ns,\ unless\ otherwise\ specified$ 

Symbol	Parameter	Conditions	Min	Тур	Max	Units
t <sub>PHL</sub>	Propagation Delay Time	$V_{DD} = 5V$		60	110	ns
	HIGH-to-LOW Level	V <sub>DD</sub> = 10V		25	55	ns
		V <sub>DD</sub> = 15V		20	30	ns
t <sub>PLH</sub>	Propagation Delay Time	$V_{DD} = 5V$		60	120	ns
	LOW-to-HIGH Level	V <sub>DD</sub> = 10V		30	55	ns
		V <sub>DD</sub> = 15V		25	45	ns
t <sub>THL</sub>	Transition Time	$V_{DD} = 5V$		30	60	ns
	HIGH-to-LOW Level	V <sub>DD</sub> = 10V		20	40	ns
		V <sub>DD</sub> = 15V		15	30	ns
t <sub>TLH</sub>	Transition Time	$V_{DD} = 5V$		60	120	ns
	LOW-to-HIGH Level	V <sub>DD</sub> = 10V		30	55	ns
		V <sub>DD</sub> = 15V		25	45	ns
C <sub>IN</sub>	Input Capacitance	Any Input		5	7.5	pF

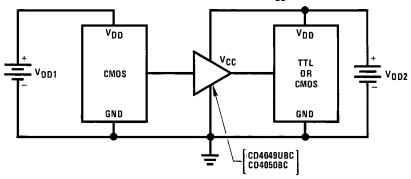
Note 6: AC Parameters are guaranteed by DC correlated testing.

# **Switching Time Waveforms**



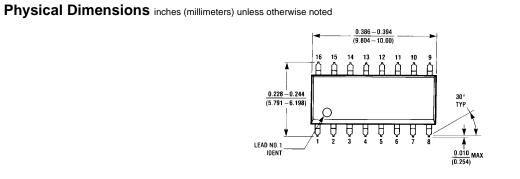
# **Typical Applications**

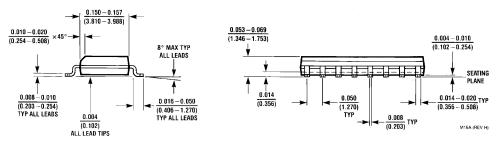
#### CMOS to TLL or CMOS at a Lower $\ensuremath{\text{V}_{\text{DD}}}$



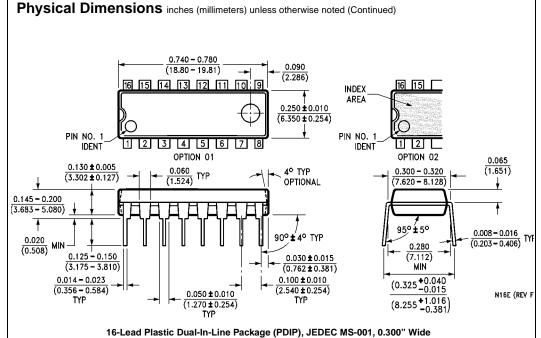
 $V_{DD1} \geq V_{DD2}$ 

In the case of the CD4049UBC the output drive capability increases with increasing input voltage. E.g., If  $V_{\rm DD1}$  = 10V the CD4049UBC could drive 4 TTL loads.





16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Package Number M16A



Package Number N16E

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